# 2SD1251, 2SD1251A

### Silicon NPN triple diffusion junction type

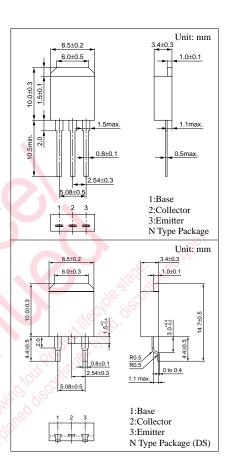
#### For power amplification

#### Features

- Wide area of safe operation (ASO)
- N type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment.

#### Absolute Maximum Ratings $(T_C=25^{\circ}C)$

Parameter		Symbol Ratings		Unit	
Collector to	2SD1251	3.7	60	v	
base voltage	2SD1251A	$V_{CBO}$	80	V	
Collector to	2SD1251	7.7	60	v	
emitter voltage	2SD1251A	$V_{CEO}$	80	V	
Emitter to base voltage		$V_{\mathrm{EBO}}$	8	v	
Peak collector current		$I_{CP}$	6	A	
Collector current		$I_{C}$	4	A	
Base current		$I_B$	1	A	
Collector power	T <sub>C</sub> =25°C	D	30	W	
dissipation	Ta=25°C	$P_{C}$	1.3	W	
Junction temperature		$T_{j}$	150	°C	
Storage temperature		$T_{ m stg}$	-55 to +150	°C	



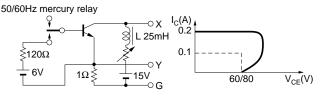
#### Electrical Characteristics (T<sub>C</sub>=25°C)

			P				
Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current		$I_{CBO}$	$V_{CB} = 20V, I_{E} = 0$			30	μΑ
Emitter cutoff current		$I_{EBO}$	$V_{EB} = 8V, I_{C} = 0$			1	mA
Collector to emitter	2SD1251	*2	$I_C = 0.2A, L = 25mH$	60			V
voltage	2SD1251A	V <sub>CEO(sus)</sub> *2		80			
Forward current transfer ratio		h <sub>FE1</sub>	$V_{CE} = 3V, I_{C} = 0.1A$	40			
		h <sub>FE2</sub> *1	$V_{CE} = 3V, I_{C} = 1A$	30		160	
Base to emitter voltage V <sub>BE</sub>		$V_{BE}$	$V_{CE} = 3V, I_C = 1A$			1.2	V
Collector to emitter saturation voltage   V <sub>CE(sat)</sub>		V <sub>CE(sat)</sub>	$I_C = 2A, I_B = 0.4A$			1	V
Transition frequency		$f_T$	$V_{CE} = 10V, I_{C} = 0.2A, f = 0.5MHz$		1		MHz

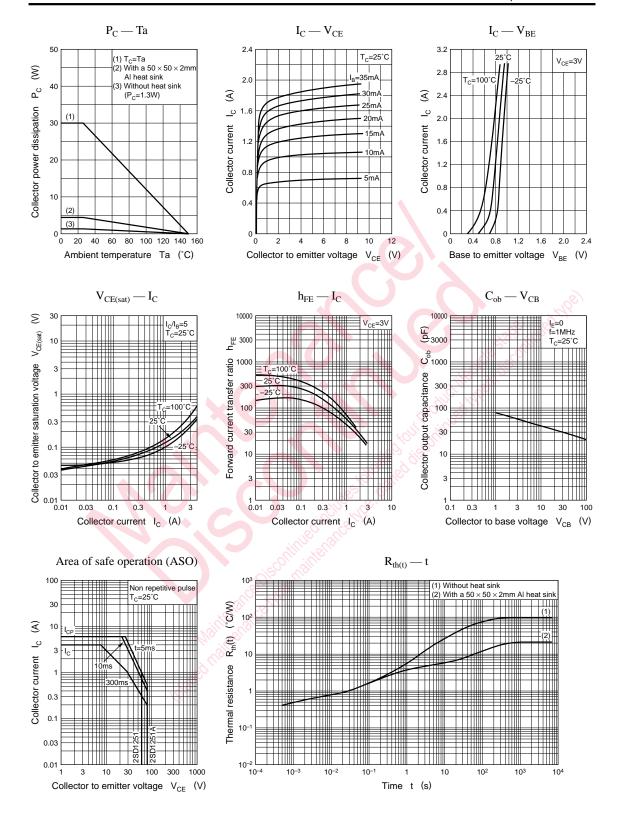
#### \*1hFE2 Rank classification

Rank	Q	P	О	
$h_{FE2}$	30 to 60	50 to 100	80 to 160	

\*2V<sub>CEO(sus)</sub> Test circuit



Note: Ordering can be made by the common rank (OP rank  $h_{FE2} = 50$  to 160) in the rank classification.



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